

**0.5A surface mount Schottky diode**

# RB0540S2

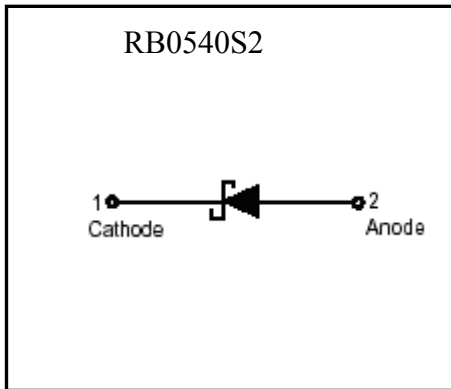
**Features**

- High current capability, low forward voltage drop
- High surge current capability
- Guardring for over voltage protection
- Low power loss, high efficiency
- Ultra high-speed switching
- Low profile surface mounted package in order to minimize board space

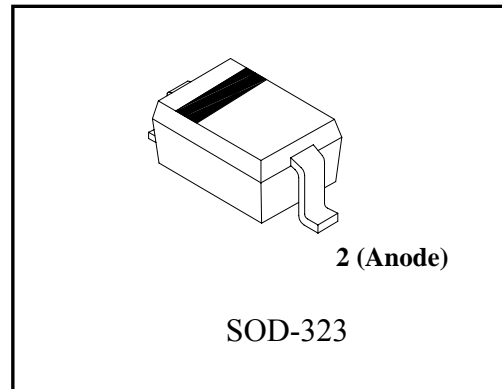
**Mechanical data**

- Case : Molded plastic, SC-76/SOD323
- Epoxy : UL94-V0 rated flame retardant
- Terminals : Plated terminals, solderable per MIL-STD-750 method 2026
- Polarity : Indicated by cathode band
- Mounting position : Any
- Weight : approx. 0.0045 gram

**Symbol**

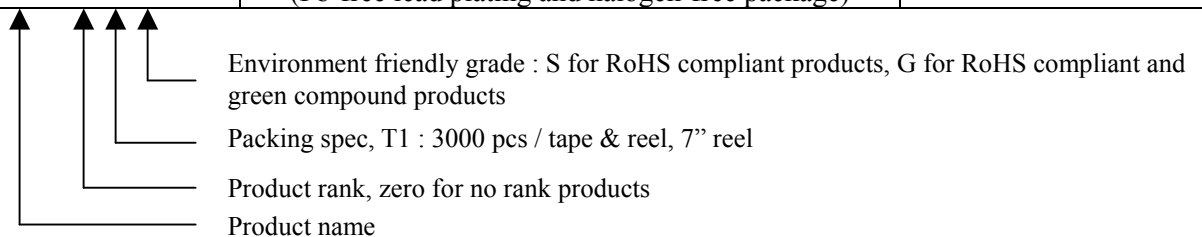


**Outline**



**Ordering Information**

| Device          | Package  | Shipping               |
|-----------------|--|------------------------|
| RB0540S2-0-T1-G | SOD-323<br>(Pb-free lead plating and halogen-free package) | 3000 pcs / tape & reel |





**Absolute Maximum Ratings** ( $T_A=25^{\circ}\text{C}$ , unless otherwise noted)

| Parameters                           | Conditions  | Symbol          | Min | Typ | Max  | Units                       |
|--------------------------------------|---|-----------------|-----|-----|------|-----------------------------|
| Repetitive peak reverse voltage      |   | $V_{RRM}$       |     |     | 40   | V                           |
| RMS voltage                          |   | $V_{RMS}$       |     |     | 28   | V                           |
| Continuous reverse voltage           |   | $V_R$           |     |     | 40   | V                           |
| Forward rectified current            |   | $I_O$           |     |     | 0.5  | A                           |
|                                      | Single phase half wave, 60Hz<br>@ $T_J=25^{\circ}\text{C}$                  | $I_{F(AV)}$     |     |     | 1    |                             |
| Forward surge current                | 8.3ms single half sine-wave<br>superimposed on rated load<br>(JEDEC method) | $I_{FSM}$       |     |     | 15   | A                           |
| Power Dissipation                    | $T_A=25^{\circ}\text{C}$  | $P_D$           |     |     | 0.2  | W                           |
|                                      |   |                 |     |     | 0.83 |                             |
| Thermal resistance                   | Junction to Ambient   | $R_{\theta JA}$ |     |     | 500  | $^{\circ}\text{C}/\text{W}$ |
|                                      | Junction to Ambient (Note)  |                 |     | 90  | 120  |                             |
| Storage temperature range            |   | $T_{stg}$       | -65 |     | 175  | $^{\circ}\text{C}$          |
| Operating junction temperature range |   | $T_J$           | -55 |     | 125  | $^{\circ}\text{C}$          |

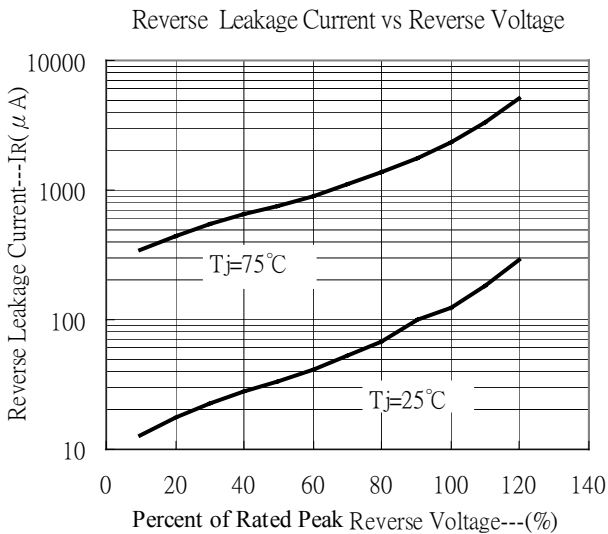
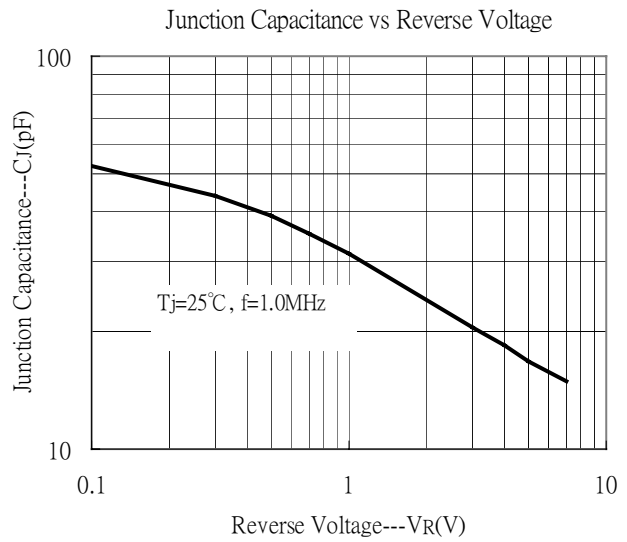
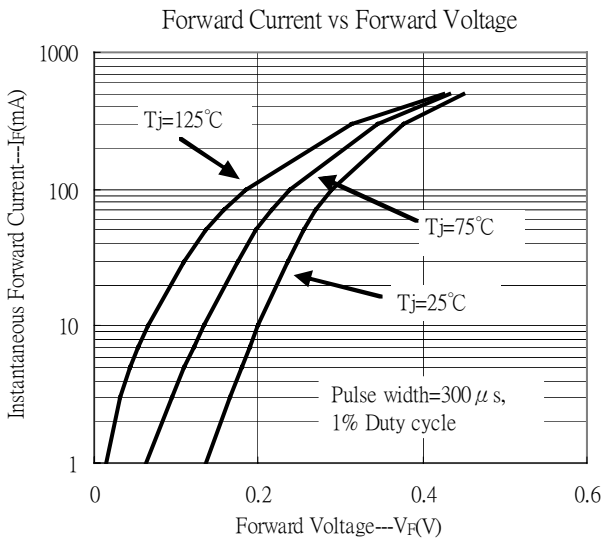
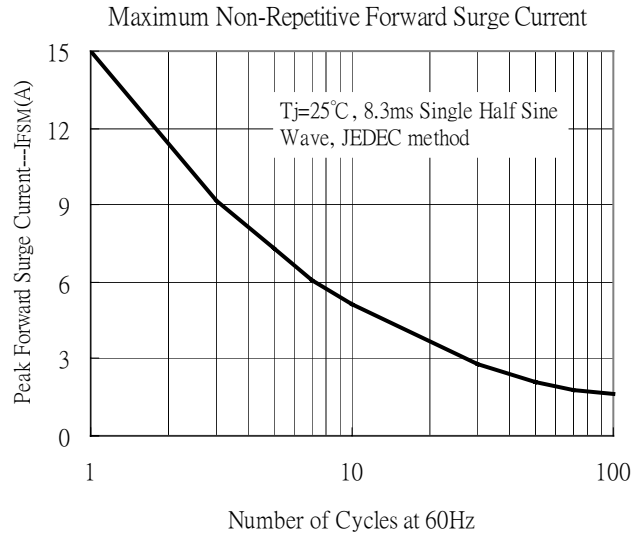
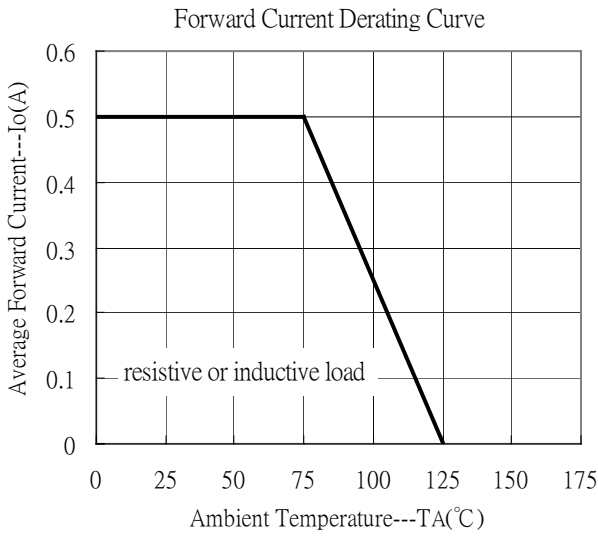
Note : When device is mounted on ceramic board with area of  $40 \times 40 \text{mm}^2$ ,  $t \leq 5\text{s}$ .

**Characteristics** ( $T_A=25^{\circ}\text{C}$ )

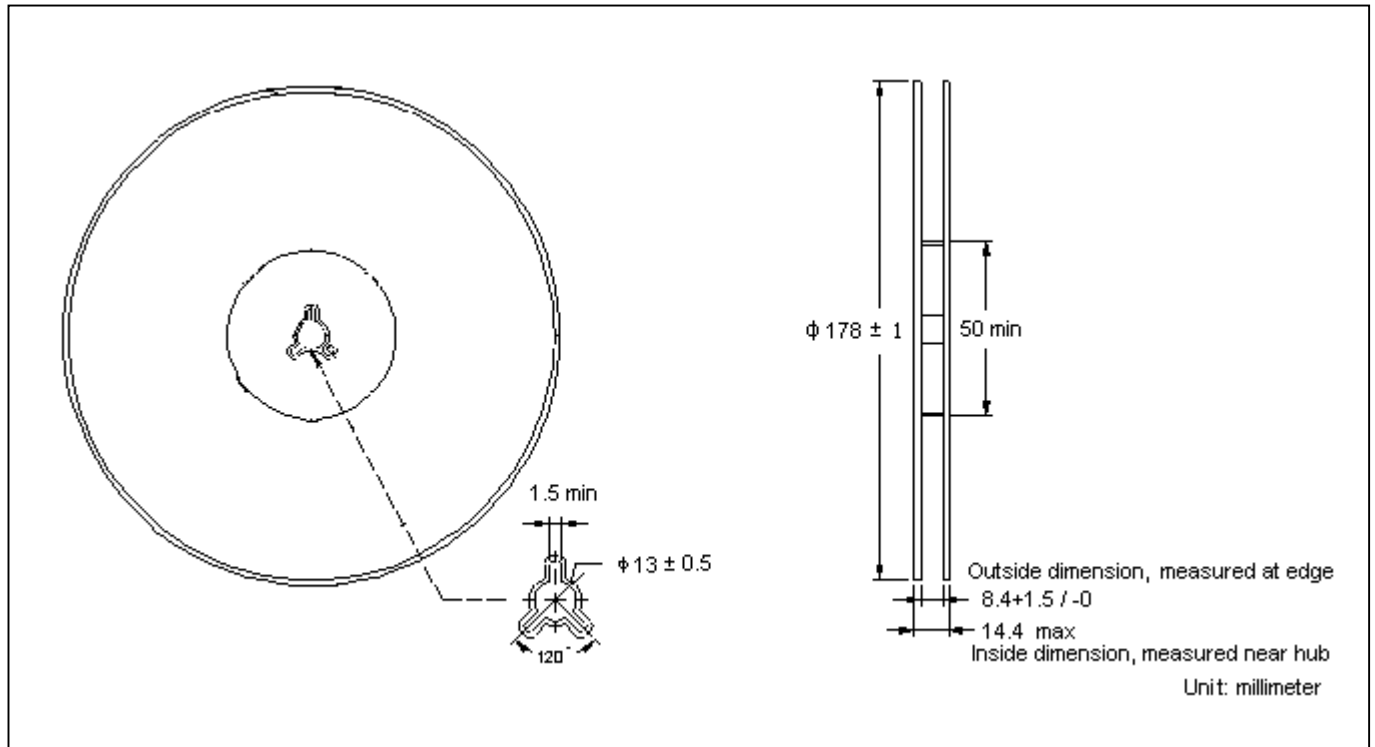
| Characteristic                | Symbol  | Condition                                | Min. | Typ  | Max. | Unit          |
|-------------------------------|---------|--|------|------|------|---------------|
|                               | $V_R$   | $I_R=600\mu\text{A}$                     | 40   | -    | -    | V             |
| Forward Voltage               | $V_F 1$ | $I_F=100\text{mA}$                       | -    | -    | 370  | mV            |
|                               | $V_F 2$ | $I_F=500\text{mA}$                       | -    | -    | 500  |               |
| Reverse Leakage Current       | $I_R 1$ | $V_R=20\text{V}$                         | -    | -    | 100  | $\mu\text{A}$ |
|                               | $I_R 2$ | $V_R=40\text{V}$                         | -    | -    | 500  | $\mu\text{A}$ |
|                               | $I_R 3$ | $V_R=40\text{V}, T_A=75^{\circ}\text{C}$ | -    | -    | 10   | mA            |
| Capacitance Between Terminals | $C_T$   | $V_R=4\text{V}, f=1\text{MHz}$           | -    | 18.3 | -    | pF            |



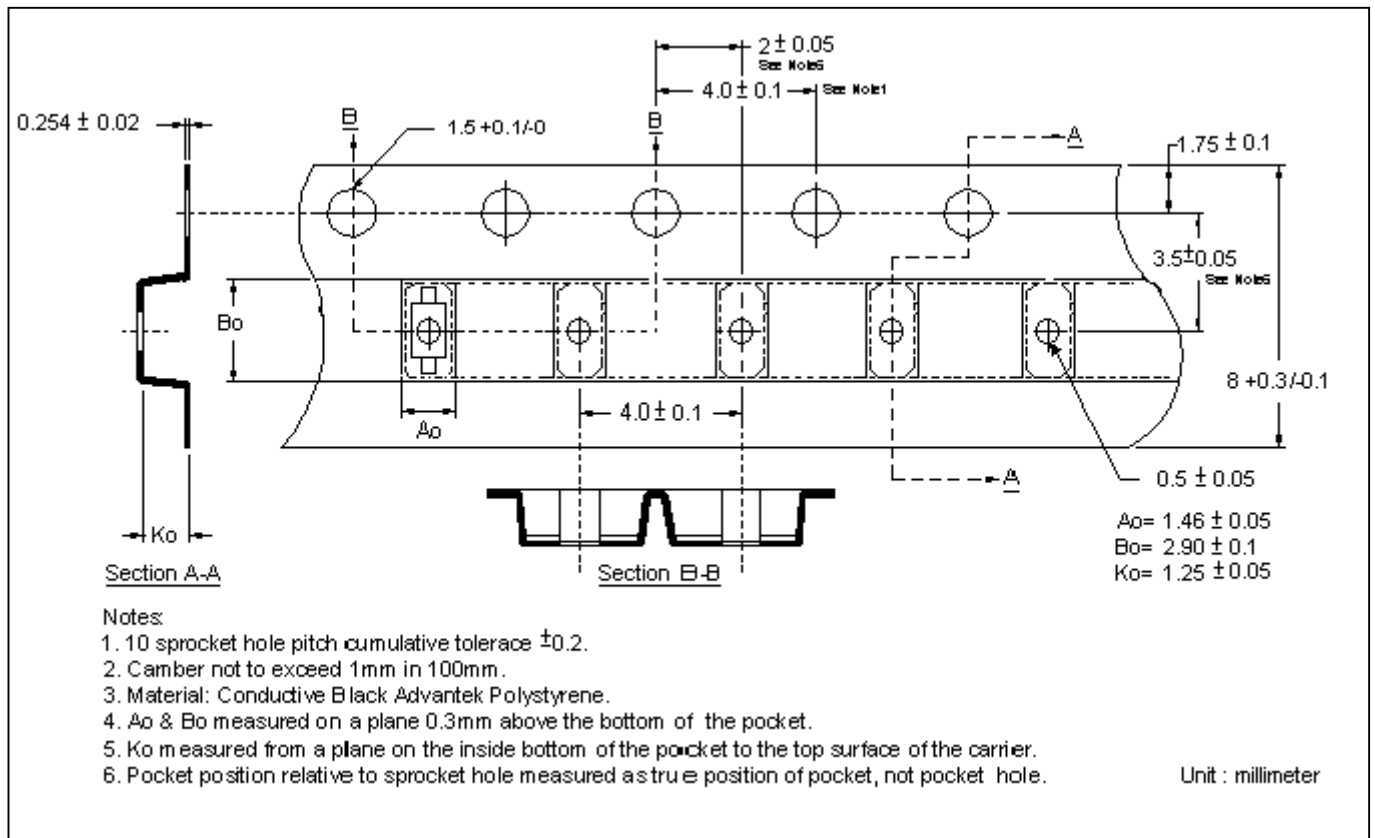
### Typical Characteristics



### Reel Dimension



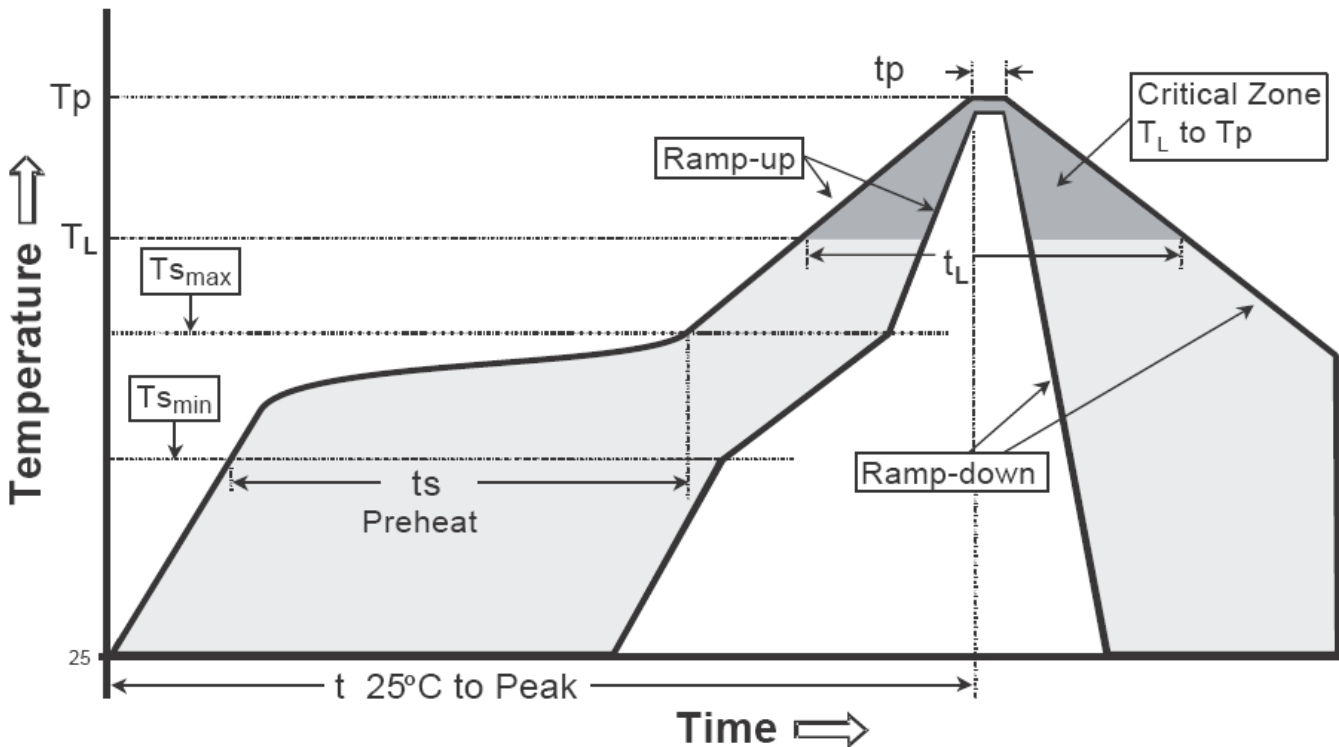
### Carrier Tape Dimension



**Recommended wave soldering condition**

|                 |                  |                 |
|-----------------|------------------|-----------------|
| Product         | Peak Temperature | Soldering Time  |
| Pb-free devices | 260 +0/-5 °C     | 5 +1/-1 seconds |

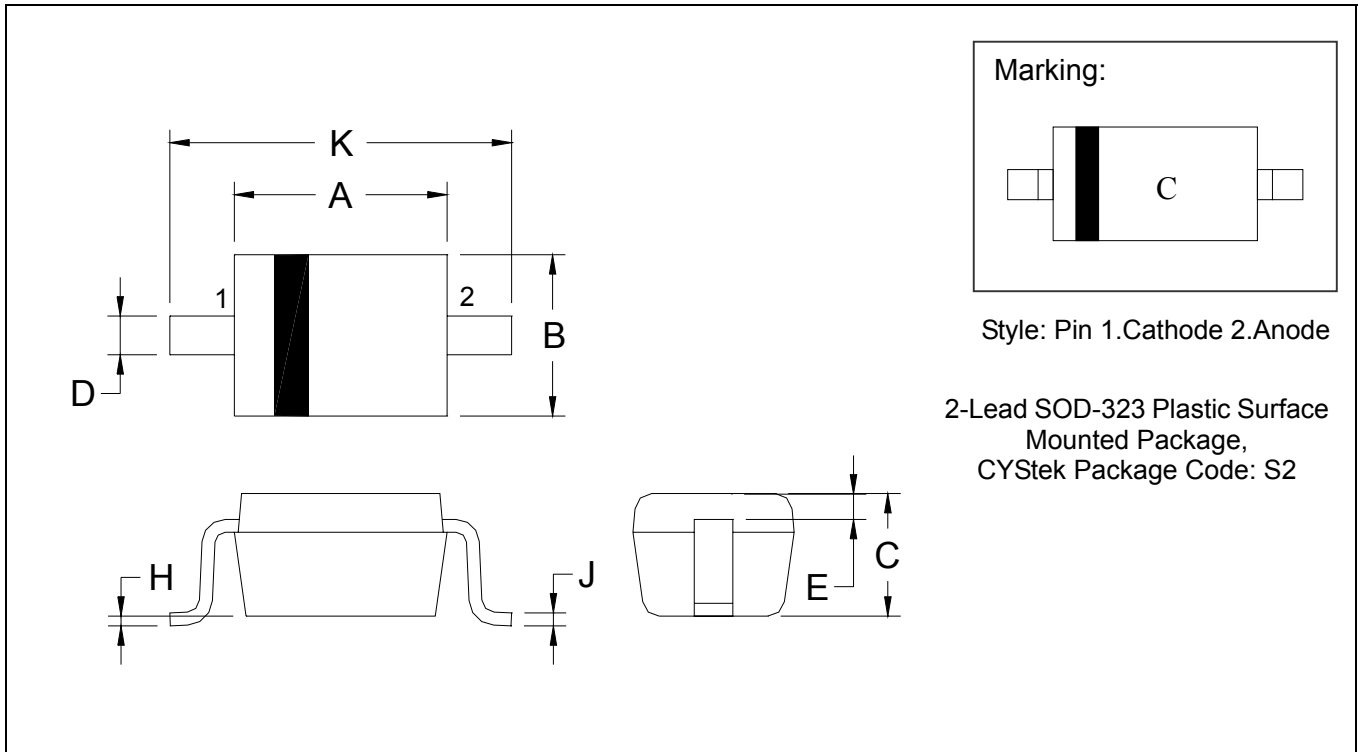
**Recommended temperature profile for IR reflow**



| Profile feature                                | Sn-Pb eutectic Assembly | Pb-free Assembly |
|--|-------------------------|------------------|
| Average ramp-up rate (Tsmax to Tp)             | 3°C/second max.         | 3°C/second max.  |
| Preheat  |                         |                  |
| -Temperature Min(Ts min)                       | 100°C                   | 150°C            |
| -Temperature Max(Ts max)                       | 150°C                   | 200°C            |
| -Time(ts min to ts max)                        | 60-120 seconds          | 60-180 seconds   |
| Time maintained above:                         |                         |                  |
| -Temperature (TL)                              | 183°C                   | 217°C            |
| - Time (tL)                                    | 60-150 seconds          | 60-150 seconds   |
| Peak Temperature(TP)                           | 240 +0/-5 °C            | 260 +0/-5 °C     |
| Time within 5°C of actual peak temperature(tp) | 10-30 seconds           | 20-40 seconds    |
| Ramp down rate                                 | 6°C/second max.         | 6°C/second max.  |
| Time 25 °C to peak temperature                 | 6 minutes max.          | 8 minutes max.   |

Note : All temperatures refer to topside of the package, measured on the package body surface.

**SOD-323 Dimension**



\*: Typical

| DIM | Inches |        | Millimeters |      | DIM | Inches     |        | Millimeters |       |
|-----|--------|--------|-------------|------|-----|------------|--------|-------------|-------|
|     | Min.   | Max.   | Min.        | Max. |     | Min.       | Max.   | Min.        | Max.  |
| A   | 0.0630 | 0.0709 | 1.60        | 1.80 | E   | 0.0060 REF |        | 0.15 REF    |       |
| B   | 0.0453 | 0.0531 | 1.15        | 1.35 | H   | 0.0000     | 0.0040 | 0.00        | 0.10  |
| C   | 0.0315 | 0.0394 | 0.80        | 1.00 | J   | 0.0035     | 0.0070 | 0.089       | 0.177 |
| D   | 0.0098 | 0.0157 | 0.25        | 0.40 | K   | 0.0906     | 0.1063 | 2.30        | 2.70  |

**Notes:** 1.Controlling dimension : millimeters.  
 2.Lead thickness specified per L/F drawing with solder plating.  
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

**Material:**

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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